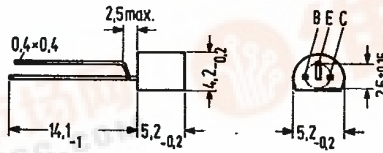


25C D ■ 8235605 0004446 8 ■ SIEG
NPN Silicon RF Transistor 25C 04446 D **BF 198**
 SIEMENS AKTIENGESELLSCHAFT T-31-21

for gain-controlled TV IF amplifier stages

BF 198 is an NPN silicon planar radio-frequency transistor in TO 92 plastic package (10 A 3 DIN 41868). The transistor is characterized by a low reverse transfer capacitance and is recommended for use in gain-controlled IF amplifier stages of TV sets in common-emitter configuration.

| Type | Ordering code |
|--------|---------------|
| BF 198 | Q62702-F354 |



Approx. weight 0.25 g Dimensions in mm

Maximum ratings

| | | | |
|---|-----------|-------------|----|
| Collector-emitter-voltage | V_{CE0} | 30 | V |
| Collector-base voltage | V_{CB0} | 40 | V |
| Base-emitter voltage | V_{EBO} | 4 | V |
| Collector current | I_C | 25 | mA |
| Base current | I_B | 3 | mA |
| Junction temperature | T_j | 150 | °C |
| Storage temperature range | T_{stg} | -55 to +150 | °C |
| Total power dissipation ($T_{amb} \leq 25^\circ\text{C}$) | P_{tot} | 500 | mW |

Thermal resistance

| | | | |
|-------------------------|------------|------------|-----|
| Junction to ambient air | R_{thJA} | ≤ 250 | K/W |
|-------------------------|------------|------------|-----|

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Static characteristics ($T_{amb} = 25^\circ\text{C}$)

| | | | |
|---|-----------|-----------|----|
| Collector cutoff current ($V_{CB} = 40\text{ V}$) | I_{CBO} | < 100 | nA |
| DC current gain ($V_{CE} = 10\text{ V}; I_C = 4\text{ mA}$) | h_{FE} | 70 (> 26) | - |
| ($V_{CE} = 3\text{ V}; I_C = 10\text{ mA}$) | h_{FE} | > 10 | - |
| Base-emitter voltage ($V_{CE} = 10\text{ V}; I_C = 4\text{ mA}$) | V_{BE} | 750 | mV |

Dynamic characteristics ($T_{amb} = 25^\circ\text{C}$)

| | | | |
|---|-------------------|------|-----|
| Transition frequency ($V_{CE} = 10\text{ V}; I_C = 4\text{ mA}; f = 100\text{ MHz}$) | f_T | 400 | MHz |
| Reverse transfer capacitance ($V_{CE} = 10\text{ V}; I_C = 1\text{ mA}; f = 1\text{ MHz}$) | $-C_{12e}$ | 0.22 | pF |
| Noise figure ($V_{CE} = 10\text{ V}; I_C = 4\text{ mA}; f = 35\text{ MHz}; R_g = 100\ \Omega$) | NF | 3 | dB |
| Obtainable power gain ($V_{CE} = 10\text{ V}; I_C = 4\text{ mA}; f = 35\text{ MHz}$) | $G_{peopt}^{(1)}$ | 42 | dB |

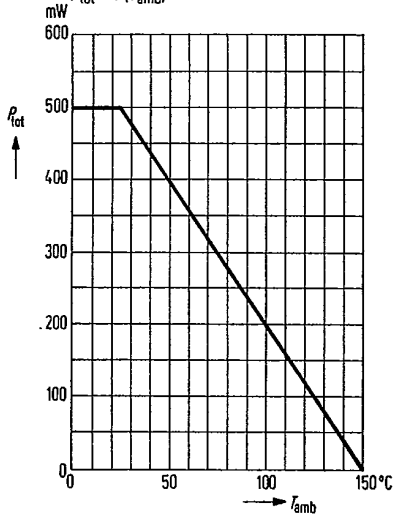
Four-pole characteristics: ($V_{CE} = 10\text{ V}; I_C = 4\text{ mA}; f = 35\text{ MHz}$)

| | | | |
|---------------------------|-------------------------------|-----------------------------|-----------------------------|
| $g_{11e} = 4,5\text{ mS}$ | $[y_{12e}] = 47\ \mu\text{S}$ | $[y_{21e}] = 105\text{ mS}$ | $g_{22e} = 40\ \mu\text{S}$ |
| $c_{11e} = 40\text{ pF}$ | $-\varphi_{12e} = 95^\circ$ | $-\varphi_{21e} = 20^\circ$ | $c_{22e} = 1,3\text{ pF}$ |

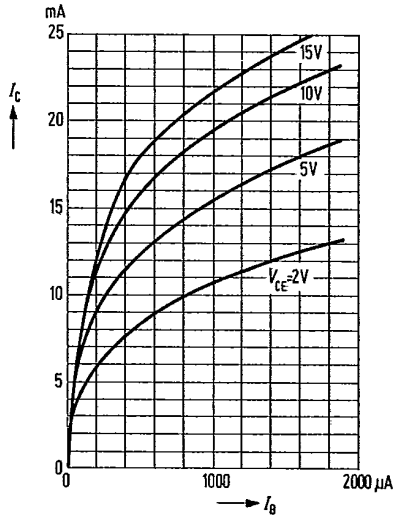
$$^1) G_{peopt} = \frac{|y_{21e}|^2}{4g_{11e} \cdot g_{22e}}$$

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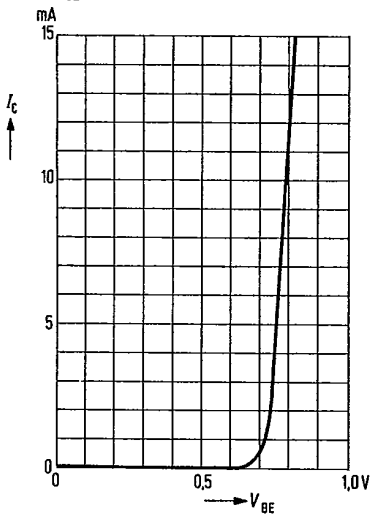
Total perm. power dissipation versus temperature
 $P_{tot} = f(T_{amb})$



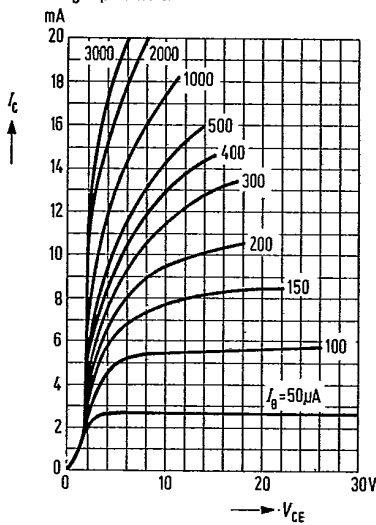
Collector current $I_C = f(I_B)$



Input characteristic $I_C = f(V_{BE})$
 $V_{CE} = 10V$

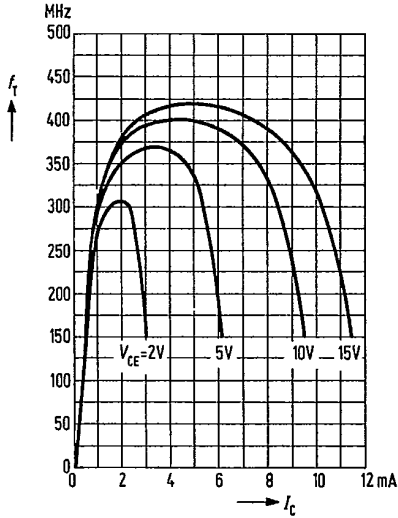


Output characteristics $I_C = f(V_{CE})$
 $I_B = \text{parameter}$

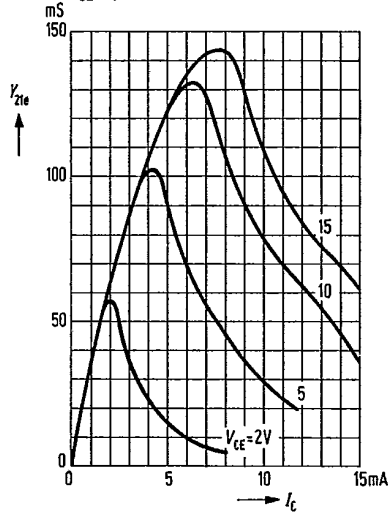


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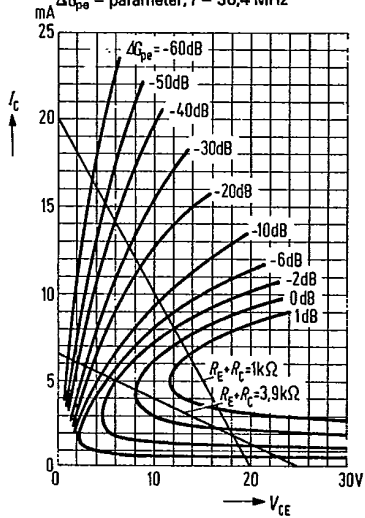
Transition frequency $f_T = f(I_C)$
 $V_{CE} = \text{parameter}$



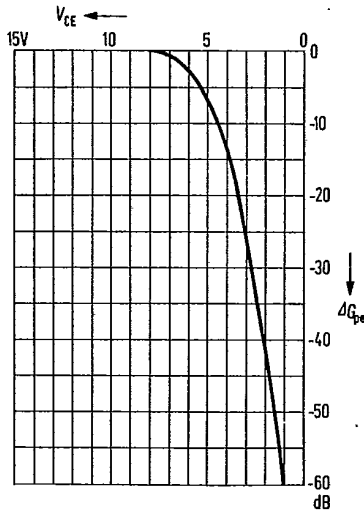
Short-circuit forward transfer admittance $y_{21e} = f(I_C)$
 $V_{CE} = \text{parameter}; f = 35 \text{ MHz}$



Constant power gain characteristics
 $I_C = f(V_{CE})$
 $\Delta G_{pe} = \text{parameter}; f = 36.4 \text{ MHz}$



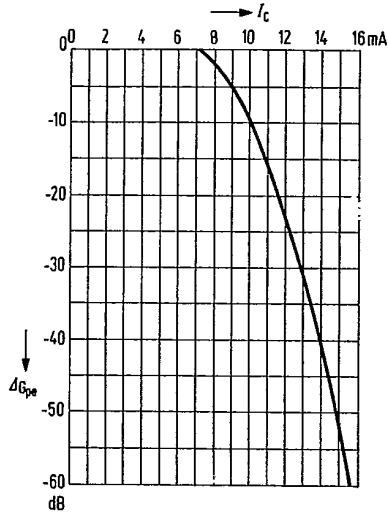
Power gain control range
 $\Delta G_{pe} = f(V_{CE}); R_E + R_C = 3.9 \text{ k}\Omega;$
 $f = 36.4 \text{ MHz}; -V_{EE} = 25 \text{ V}$



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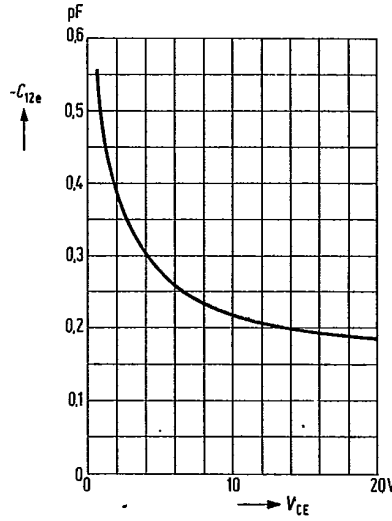
Control range of power gain

$\Delta G_{pe} = f(I_C); R_E + R_C = 1 \text{ k}\Omega;$
 $-V_{EE} = 20 \text{ V}; f = 36.4 \text{ MHz}$

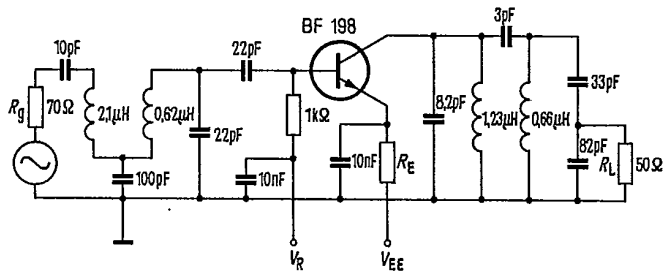


Reverse transfer capacitance

$C_{12e} = f(V_{CE}); I_C = 1 \text{ mA}; f = 1 \text{ MHz}$



First stage of a TV IF amplifier incl. voltage gain control $f = 36.4 \text{ MHz}$.



Power gain ($I_C = 4 \text{ mA};$
 $-V_{EE} = 25 \text{ V}; R_E + R_C = 3.9 \text{ k}\Omega$)
 Gain control range

| | | |
|--------------|----|----|
| G_p | 26 | dB |
| ΔG_p | 60 | dB |